

4V Drive Nch MOSFET

RSR030N06

●Structure

Silicon N-channel MOSFET

●Features

- 1) Low On-resistance.
- 2) Small Surface Mount Package (TSMT3).

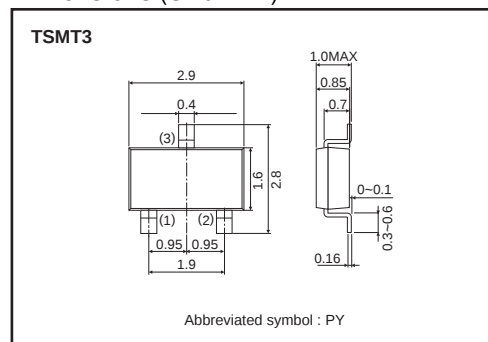
●Application

Switching

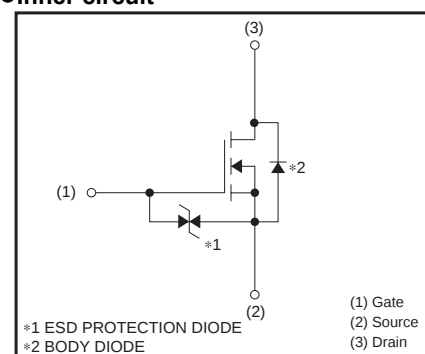
●Packaging specifications

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	3000
RSR030N06		○

●Dimensions (Unit : mm)



●Inner circuit



●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Drain-source voltage	V_{DS}	60	V
Gate-source voltage	V_{GS}	± 20	V
Drain current	Continuous	I_D	± 3 A
	Pulsed	I_{DP} *1	± 12 A
Source current (Body diode)	Continuous	I_S	0.8 A
	Pulsed	I_{SP} *1	12 A
Total power dissipation	P_D *2	1.0	W
Channel temperature	T_{ch}	150	°C
Range of storage temperature	T_{stg}	-55 to +150	°C

*1 $P_w \leq 10 \mu s$, Duty cycle $\leq 1\%$

*2 When mounted on a ceramic board

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th(ch-a)}$ *	125	°C/W

* When mounted on a ceramic board

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	—	—	±10	μA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	60	—	—	V	$I_D = 1mA$, $V_{GS} = 0V$
Zero gate voltage drain current	I_{DSS}	—	—	1	μA	$V_{DS} = 60V$, $V_{GS} = 0V$
Gate threshold voltage	$V_{GS(th)}$	1.0	—	2.5	V	$V_{DS} = 10V$, $I_D = 1mA$
Static drain-source on-state resistance	$R_{DS(on)}$	—	60	85	mΩ	$I_D = 3A$, $V_{GS} = 10V$
		—	70	100	mΩ	$I_D = 3A$, $V_{GS} = 4.5V$
		—	75	105	mΩ	$I_D = 3A$, $V_{GS} = 4V$
Forward transfer admittance	$ Y_{fs} $	2.1	—	—	S	$V_{DS} = 10V$, $I_D = 3A$
Input capacitance	C_{iss}	—	380	—	pF	$V_{DS} = 10V$
Output capacitance	C_{oss}	—	95	—	pF	$V_{GS} = 0V$
Reverse transfer capacitance	C_{rss}	—	45	—	pF	$f = 1MHz$
Turn-on delay time	$t_{d(on)}$	—	8	—	ns	$V_{DD} \approx 30V$
Rise time	t_r	—	12	—	ns	$I_D = 1.5A$
Turn-off delay time	$t_{d(off)}$	—	30	—	ns	$V_{GS} = 10V$
Fall time	t_f	—	10	—	ns	$R_L \approx 20\Omega$
Total gate charge	Q_g	—	5.0	—	nC	$V_{DD} \approx 30V$ $R_L \approx 10\Omega$
Gate-source charge	Q_{gs}	—	1.6	—	nC	$I_D = 3A$ $R_G = 10\Omega$
Gate-drain charge	Q_{gd}	—	1.4	—	nC	$V_{GS} = 5V$

*Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{SD}	—	—	1.2	V	$I_S = 3A$, $V_{GS} = 0V$

*Pulsed

●Electrical characteristics curves

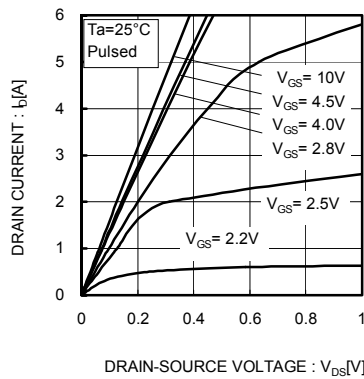


Fig.1 Typical Output Characteristics(I)

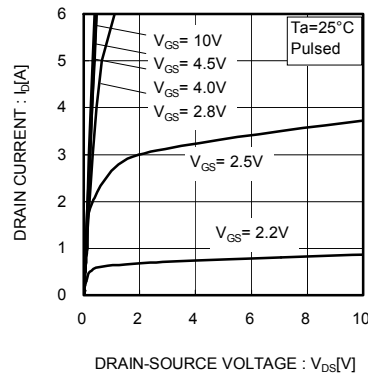


Fig.2 Typical Output Characteristics(II)

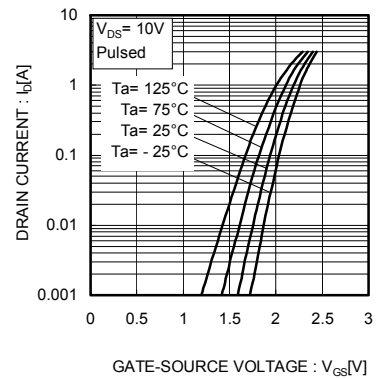


Fig.3 Typical Transfer Characteristics

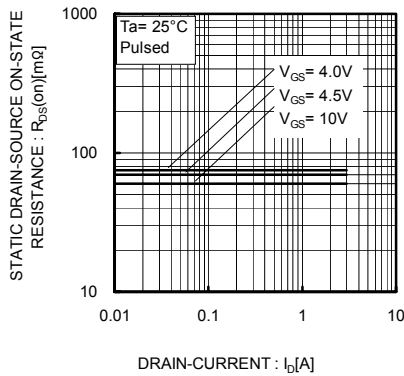


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current(I)

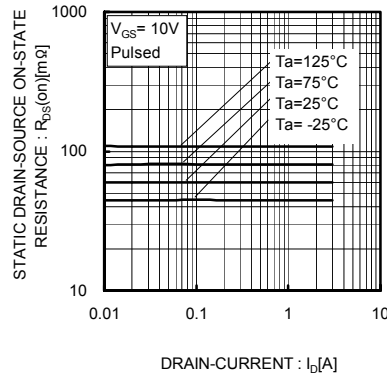


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II)

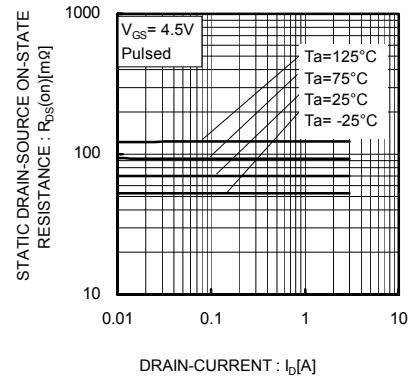


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(III)

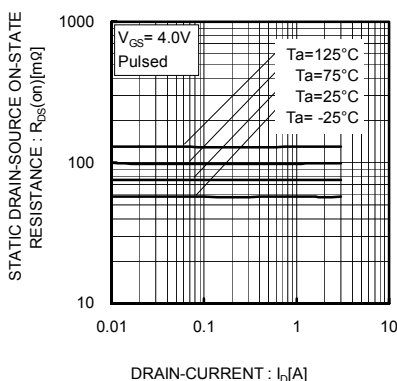


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(IV)

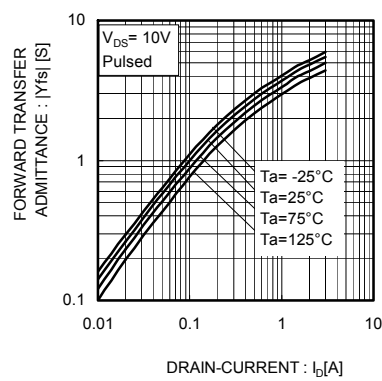


Fig.8 Forward Transfer Admittance vs. Drain Current

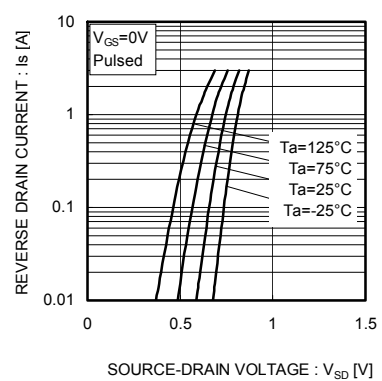


Fig.9 Reverse Drain Current vs. Source-Drain Voltage

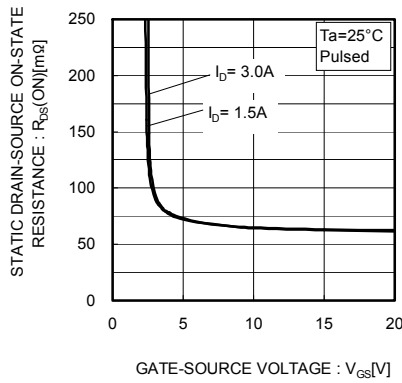


Fig.10 Static Drain-Source On-State Resistance vs. Gate Source Voltage

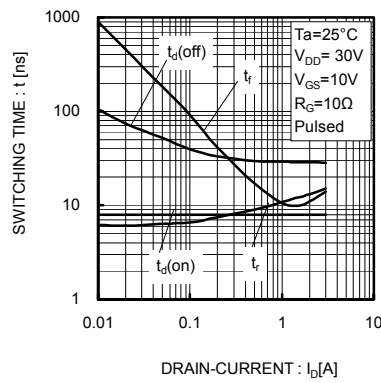


Fig.11 Switching Characteristics

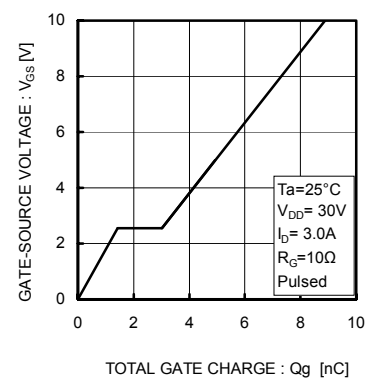


Fig.12 Dynamic Input Characteristics

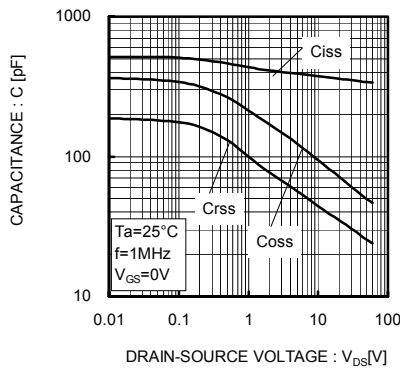


Fig.13 Typical Capacitance vs. Drain-Source Voltage

●Measurement circuits

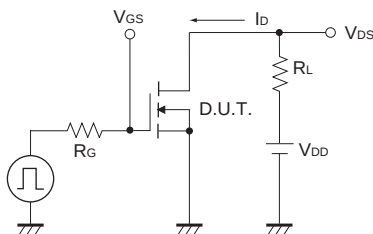


Fig.1-1 Switching time measurement circuit

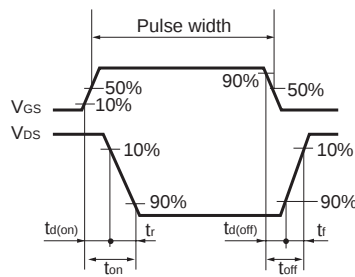


Fig.1-2 Switching waveforms

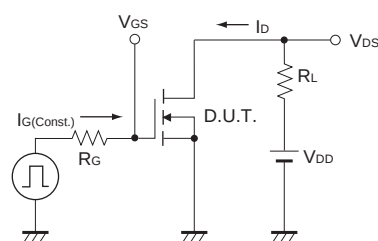


Fig.2-1 Gate charge measurement circuit

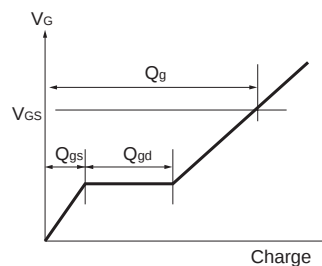


Fig.2-2 Gate charge waveform

Notes

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